# NSN 5962-01-124-9544

Memory Microcircuit - Page 1 of 1



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Body Length:
0.840 inches
Body Width:
0.310 inches
Body Height:

0.185 inches

**Maximum Power Dissipation Rating:** 

794.0 milliwatts

**Operating Tempurature Range:** 

-55.0/+125.0 degrees celsius

### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### Features Provided:

Monolithic and bipolar and schottky

#### **Inclosure Material:**

Ceramic

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

# Input Circuit Pattern:

10 input

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

## **Time Rating Per Chacteristic:**

85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Prom

### **Terminal Type And Quantity:**

16 printed circuit

### Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

## Fiig:

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